Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Ceramic

Overall Length:

Between 0.140 inches and 0.163 inches

Overall Diameter:

Between 0.118 inches and 0.124 inches

Mounting Facility Quantity:

2

Mounting Method:

Compression

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

120.0 breakover voltage, dc and 180.0 breakover voltage, dc

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-emitter absolute

Maximum Operating Tempurature Per Measurement Point:

-55.0 degrees celsius case and 200.0 degrees celsius case

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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